



BYD13GGPHE3/73



Vishay / Semiconductor - Diodes Division

DIODE GEN PURP 400V 1A DO204AL Lead free / RoHS Compliant Discrete Semiconductor Products

BYD13GGPHE3/73.pdf



Out Stock 0 pcs Mininum:1 Multiples:100 Manufacturer lead time 10 weeks

We can supply BYD13GGPHE3/73, use the request quote form to request BYD13GGPHE3/73 pirce and lead time.Zeano is a professional electronic components distributor. With 3+ Million line items of available electronic components can ship in short lead-time, over 250 thousand part numbers of electronic components in stock for immediately delivery, which may include part number BYD13GGPHE3/73.The price and lead time for BYD13GGPHE3/73 depending on the quantity required and warehouse location.contact us and our sales representative will provide you price. We look forward to work with you.

Shopping Process

12Confirm the productsubmit the order	3 4 5 payment wait for delivery receive the goods
Specifications	
Voltage - Forward (Vf) (Max) @ If:	1.1V @ 1A
Voltage - DC Reverse (Vr) (Max):	400V
Supplier Device Package:	DO-204AL (DO-41)
Speed:	Standard Recovery >500ns, > 200mA (Io)
Series:	-
Reverse Recovery Time (trr):	3µs
Packaging:	Tape & Box (TB)
Package / Case:	DO-204AL, DO-41, Axial
Operating Temperature - Junction:	-65°C ~ 175°C
Mounting Type:	Through Hole
Diode Type:	Standard
Current - Reverse Leakage @ Vr:	5µA @ 200V

Current -	Average	Rectified	(Io):
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Capacitance @ Vr, F:

1A 8pF @ 4V, 1MHz

Related products

BYD13JGPHE3/73	BYD13KGP-E3/54	BYD13DGPHE3/54	BYD13GGP-E3/54	BYD13GGP-E3/73
DIODE GEN PURP 600V 1A DO204AL	DIODE GEN PURP 800V 1A DO204AL	DIODE GEN PURP 200V 1A DO204AL	DIODE GEN PURP 400V 1A DO204AL	DIODE GEN PURP 400V 1A DO204AL
Vishay Semiconductor Diodes Division				
RFQ	RFQ	RFQ	RFQ	RFQ
BYD13JGP-E3/73	BYD13GGPHE3/54	BYD13JGP-E3/54	BYD13DGPHE3/73	BYD13JGPHE3/54
DIODE GEN PURP 600V 1A DO204AL	DIODE GEN PURP 400V 1A DO204AL	DIODE GEN PURP 600V 1A DO204AL	DIODE GEN PURP 200V 1A DO204AL	DIODE GEN PURP 600V 1A DO204AL
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RFQ	RFQ	RFQ	RFQ	RFQ

Guess You May Looking For

SIT1602BC-73-XXN- 4.096000D -20 TO 70C, 2016, 50PPM, 2.25V-3 SITIME	SIT1602BI-33-18N- 19.200000T -40 TO 85C, 5032, 50PPM, 1.8V, 1 SITIME	Бите SIT1602BC-72-XXE- 38.00000E -20 ТО 70С, 2016, 25РРМ, 2.25V-3 SITIME	SIT1602BI-33-28E- 33.333000T -40 TO 85C, 5032, 50PPM, 2.8V, 3 SITIME	Били SIT1602BC-11-XXS- 66.600000Е -20 ТО 70С, 2520, 20РРМ, 2.25V-3 SITIME
RFQ	RFQ	RFQ	RFQ	RFQ
••••••••••••••••••••••••••••••••••••	SIT8008AI-83-33E- 25.000009 OSC MEMS 25.0000MHZ LVCMOS SMD	Image: wide of the system SIT1602BI-21-18E-8.192000E -40 TO 85C, 3225, 20PPM, 1.8V, 8 SITIME	БТТЕО2ВІ-81-28Е- 24.576000Т -40 ТО 85С, 7050, 20РРМ, 2.8V, 2	SIT8008BI-12-33S- 80.00000D OSC MEMS 80.0000MHZ LVCMOS SMD
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